

## WIDE BAND LOW NOISE AMPLIFIER GaAs MMIC

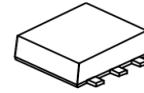
### ■ GENERAL DESCRIPTION

The NJG1142KA1 is a wide band low noise amplifier GaAs MMIC designed for mobile TV application. And this amplifier can be tuned to wide frequency (170MHz~900MHz).

The NJG1142KA1 has a LNA pass-through function to select high gain mode or low gain mode by low control voltage operation. The NJG1142KA1 features low current consumption, high linearity.

An ultra-small and ultra-thin package of FLP6-A1 is adopted.

### ■ PACKAGE OUTLINE



NJG1142KA1

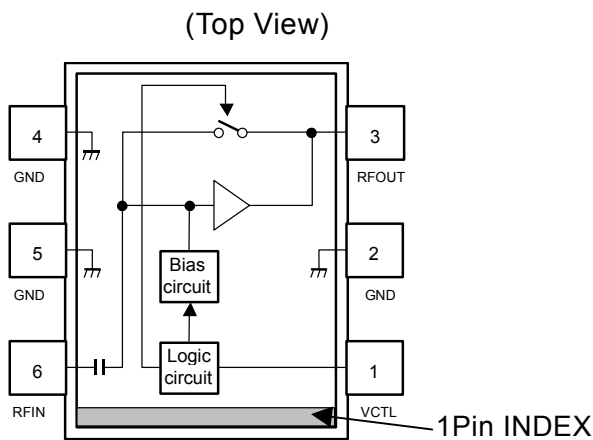
### ■ APPLICATIONS

- Wide band applications from 170MHz to 900MHz
- Mobile TV and Digital TV applications
- Mobile phone and tablet PC applications

### ■ FEATURES

- Wide operating frequency range 170MHz~900MHz
- Low voltage operation +2.8V/+1.8V typ.
- [High gain mode]
  - Low current consumption 6mA typ. @Vdd=2.8V
  - High gain +14.0dB typ. @Vdd=2.8V
  - Low noise figure 1.5dB typ. @Vdd=2.8V
  - High P<sub>-0.1dB</sub> Compression 0dBm typ. @Vdd=2.8V
  - High input IP3 +2.0dBm typ. @Vdd=2.8V
- [Low gain mode]
  - Low current consumption 11μA typ. @Vdd=2.8V
  - Gain (Low loss) -1.0dB typ. @Vdd=2.8V
  - High P<sub>-0.1dB</sub> Compression +17dBm typ. @Vdd=2.8V
  - High input IP3 +22.0dBm typ. @Vdd=2.8V
- External components count 3 pcs. (capacitor: 2pcs, inductor: 1pc)
- Small package size FLP6-A1 (package size: 1.6mm x 1.6mm x 0.55mm typ.)
- RoHS compliant and Halogen Free

### ■ PIN CONFIGURATION



### ■ PIN CONNECTION

1. VCTL
2. GND
3. RFOUT
4. GND
5. GND
6. RFIN

### ■ TRUTH TABLE

“H” = V<sub>CTL(H)</sub> “L” = V<sub>CTL(L)</sub>

V <sub>CTL</sub>	LNA Mode
H	High Gain Mode
L	Low Gain Mode

**NOTE:** The information on this datasheet is subject to change without notice

# NJG1142KA1

## ■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_l=50\ \text{ohm}$

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	$V_{DD}$		5.0	V
Control voltage	$V_{CTL}$		5.0	V
Input power	$P_{IN}$	$V_{DD}=2.8\text{V}$	+15	dBm
Power dissipation	$P_D$	4-layer FR4 PCB with through-hole (74.2mmx74.2mm), $T_j=150^{\circ}\text{C}$	580	mW
Operating temperature	$T_{opr}$		-40~+85	$^{\circ}\text{C}$
Storage temperature	$T_{stg}$		-55~+150	$^{\circ}\text{C}$

## ■ ELECTRICAL CHARACTERISTICS 1

### DC CHARACTERISTICS

General conditions:  $V_{DD}=2.8\text{V}$ ,  $T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_l=50\ \text{ohm}$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating voltage	$V_{DD}$		2.3	2.8	3.6	V
Control voltage (High)	$V_{CTL(H)}$		1.3	1.8	3.6	V
Control voltage (Low)	$V_{CTL(L)}$		0.0	0.0	0.5	V
Operating current1	$I_{DD1}$	RF OFF, $V_{CTL}=1.8\text{V}$	-	6.0	9.5	mA
Operating current2	$I_{DD2}$	RF OFF, $V_{CTL}=0\text{V}$	-	11.0	25.0	$\mu\text{A}$
Control current	$I_{CTL}$	RF OFF, $V_{CTL}=1.8\text{V}$	-	6.0	10.0	$\mu\text{A}$

## ■ ELECTRICAL CHARACTERISTICS 1

### RF CHARACTERISTICS1 (High Gain Mode)

Conditions:  $V_{DD}=2.8V$ ,  $V_{CTL}=1.8V$ ,  $f_{RF}=170\sim 900MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50ohm$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain1	Gain1	Exclude PCB, connector losses*1	11.0	14.0	18.0	dB
Noise figure1	NF1	Exclude PCB & connector losses*2	-	1.5	1.9	dB
Input power 1dB gain compression1	$P_{-1dB(IN)1}$		-5.0	0.0	-	dBm
Input 3rd order intercept point1	IIP3_1	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{IN}=-26dBm$	-3.0	+2.0	-	dBm
Isolation1	ISL1	Exclude PCB & connector losses*1	-	-19	-	dB
RF IN VSWR1	VSWRi1		-	1.5	2.3	-
RF OUT VSWR1	VSWRo1		-	1.5	2.2	-

\*1 Input & output PCB and connector losses:

0.035dB(at 170MHz), 0.088dB(620MHz), 0.120dB(at 900MHz)

\*2 Input PCB and connector losses:

0.018dB(170MHz), 0.044dB(620MHz), 0.060dB(900MHz)

## ■ ELECTRICAL CHARACTERISTICS 1

### RF CHARACTERISTICS2 (Low Gain Mode)

Conditions:  $V_{DD}=2.8V$ ,  $V_{CTL}=0V$ ,  $f_{RF}=170\sim 900MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50ohm$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain2	Gain2	Exclude PCB & connector losses*1	-2.5	-1.0	-	dB
Input power at 1dB gain compression2	$P_{-1dB(IN)2}$		+14.0	+17.0	-	dBm
Input 3rd order intercept point2	IIP3_2	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{IN}=-8dBm$	+17.0	+22.0	-	dBm
RF IN VSWR2	VSWRi2		-	1.5	2.0	-
RF OUT VSWR2	VSWRo2		-	1.5	2.0	-

\*1 Input & output PCB and connector losses:

0.035dB(at 170MHz), 0.088dB(620MHz), 0.120dB(at 900MHz)

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## ■ ELECTRICAL CHARACTERISTICS 2

### DC CHARACTERISTICS

General conditions:  $V_{DD}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\text{ ohm}$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating voltage	$V_{DD}$		-	1.8	-	V
Control voltage (High)	$V_{CTL(H)}$		-	1.8	-	V
Control voltage (Low)	$V_{CTL(L)}$		-	0.0	-	V
Operating current1	$I_{DD1}$	RF OFF, $V_{CTL}=1.8V$	-	4.2	-	mA
Operating current2	$I_{DD2}$	RF OFF, $V_{CTL}=0V$	-	6.4	-	$\mu A$
Control current	$I_{CTL}$	RF OFF, $V_{CTL}=1.8V$	-	5.6	-	$\mu A$

## ■ ELECTRICAL CHARACTERISTICS 2

### RF CHARACTERISTICS1 (High Gain Mode)

Conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=1.8V$ ,  $f_{RF}=170\sim 900MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50ohm$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain1	Gain1	Exclude PCB, connector losses*1	-	12.1	-	dB
Noise figure1	NF1	Exclude PCB & connector losses*2	-	1.75	-	dB
Input power 1dB gain compression1	$P_{-1dB(IN)1}$		-	-1.6	-	dBm
Input 3rd order intercept point1	IIP3_1	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{IN}=-26dBm$	-	+2.0	-	dBm
Isolation1	ISL1	Exclude PCB & connector losses*1	-	-18.4	-	dB
RF IN VSWR1	VSWRi1		-	1.67	-	-
RF OUT VSWR1	VSWRo1		-	1.96	-	-

\*1 Input and output PCB, connector losses :

0.035dB(at 170MHz), 0.088dB(at 620MHz), 0.120dB(at 900MHz)

\*2 Input PCB, connector losses :

0.018dB(at 170MHz), 0.044dB(at 620MHz), 0.060dB(at 900MHz)

**■ ELECTRICAL CHARACTERISTICS 2**  
**RF CHARACTERISTICS2 (Low Gain Mode)**

Conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=0V$ ,  $f_{RF}=170\sim 900MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50ohm$ , with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain2	Gain2	Exclude PCB & connector losses*1	-	-1.1	-	dB
Input power at 1dB gain compression2	$P_{-1dB(IN)2}$		-	+18.9	-	dBm
Input 3rd order intercept point2	IIP3_2	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{IN}=-8dBm$	-	+24.0	-	dBm
RF IN VSWR2	VSWRi2		-	1.33	-	-
RF OUT VSWR2	VSWRo2		-	1.15	-	-

\*1 Input and output PCB, connector losses :

0.035dB(at 170MHz), 0.088dB(at 620MHz), 0.120dB(at 900MHz)

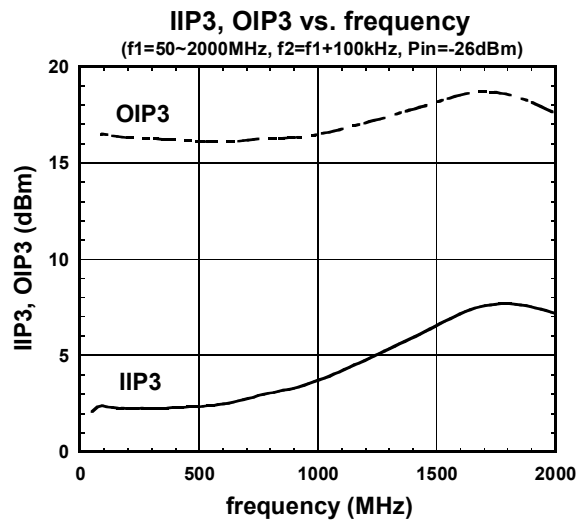
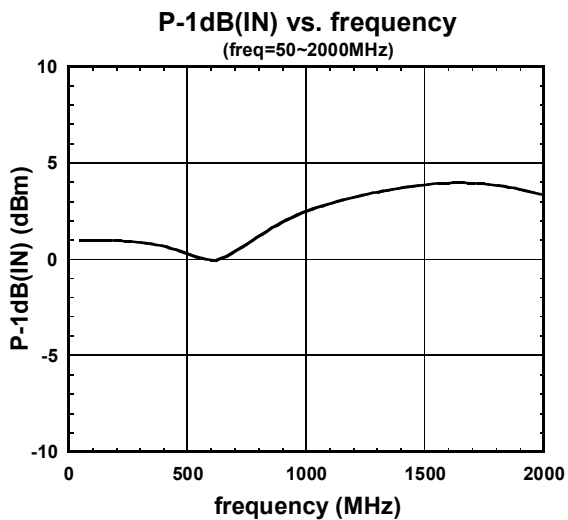
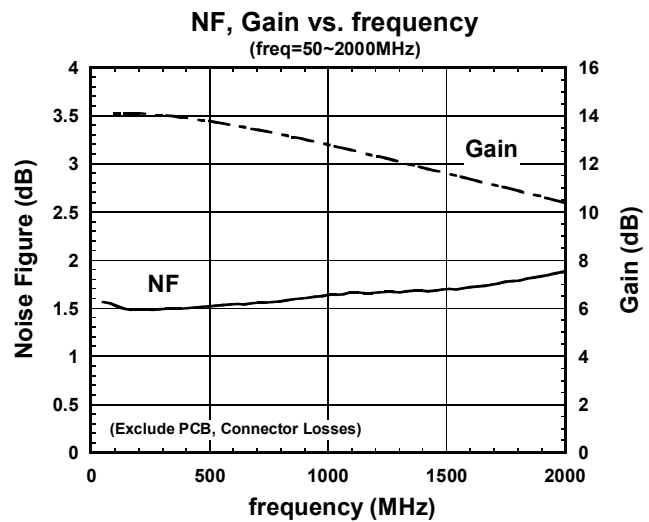
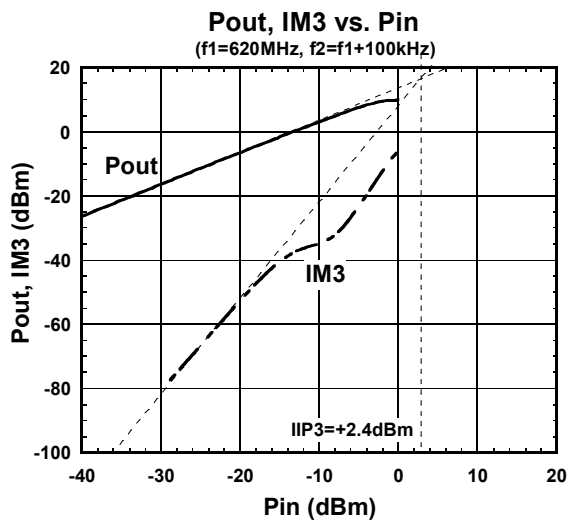
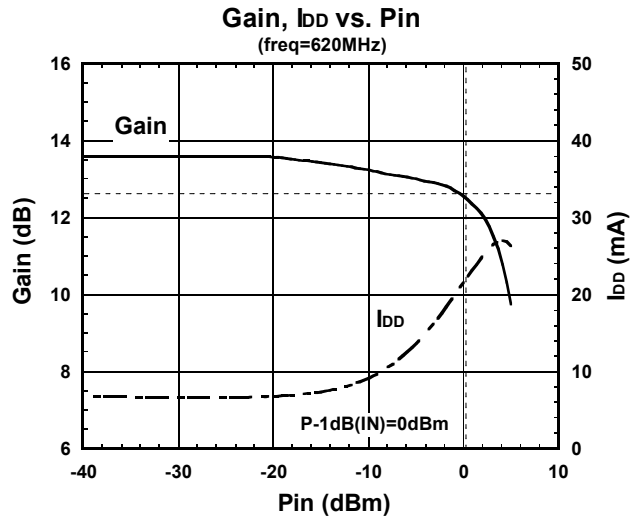
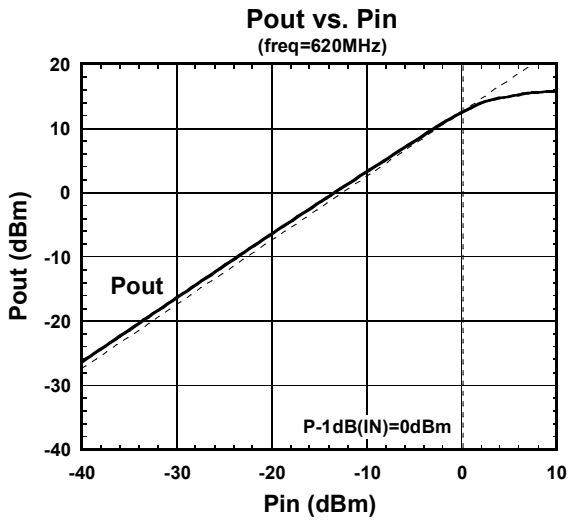
**■ TERMINAL INFORMATION**

No.	SYMBOL	DESCRIPTION
1	VCTL	Control voltage supply terminal.
2	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
3	RFOUT	RF output terminal. This terminal is also the power supply terminal of the LNA. please use inductor (L1) to connect power supply.
4	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.。
5	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
6	RFIN	RF input terminal. This IC is integrated an input DC blocking capacitor.

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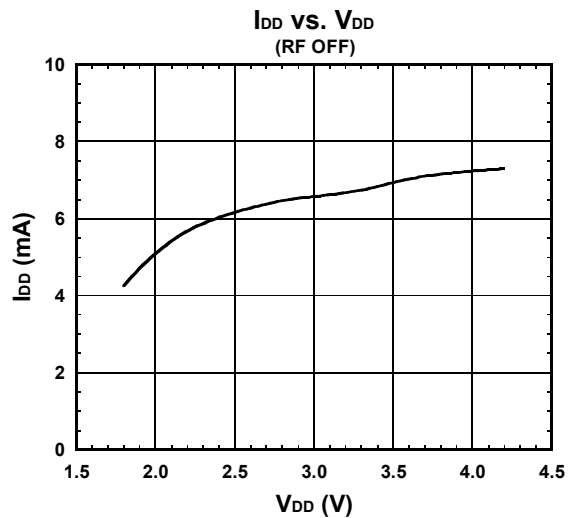
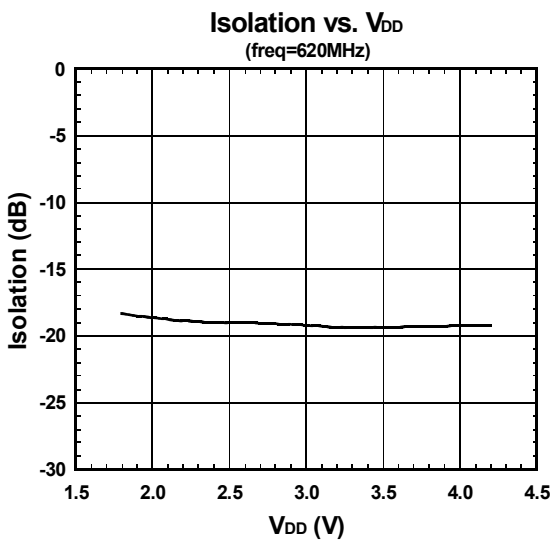
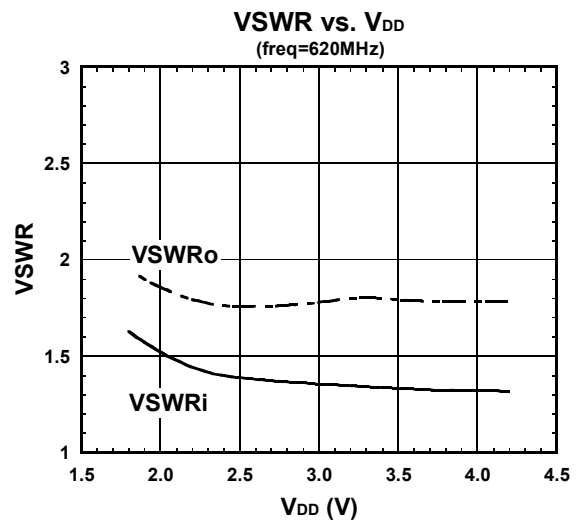
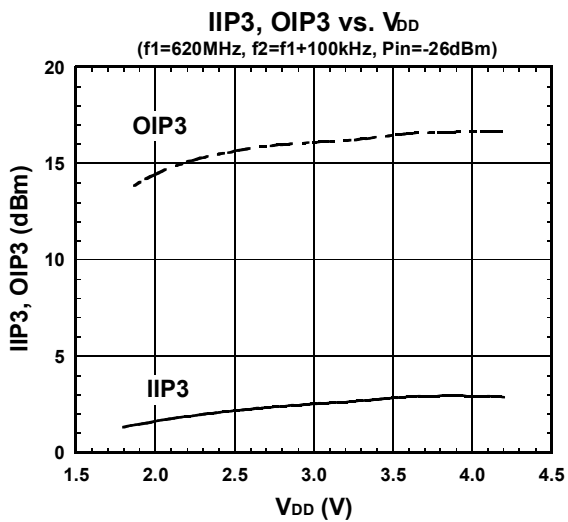
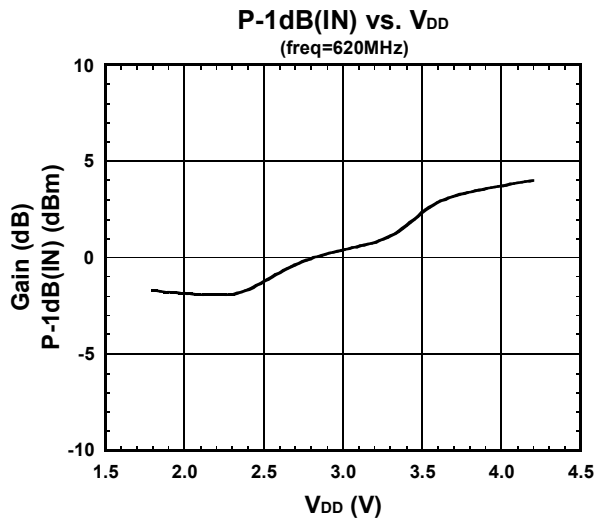
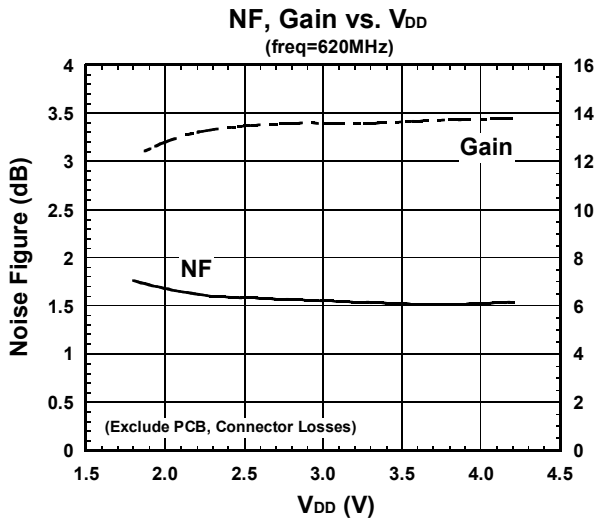
## ■ ELECTRICAL CHARACTERISTICS (High Gain Mode)

(Condition :  $T_a=+25^\circ\text{C}$ ,  $V_{DD}=2.8\text{V}$ ,  $V_{CTL}=1.8\text{V}$ ,  $Z_s=Z_l=50\text{ohm}$ , with application circuit)



## ■ ELECTRICAL CHARACTERISTICS (High Gain Mode)

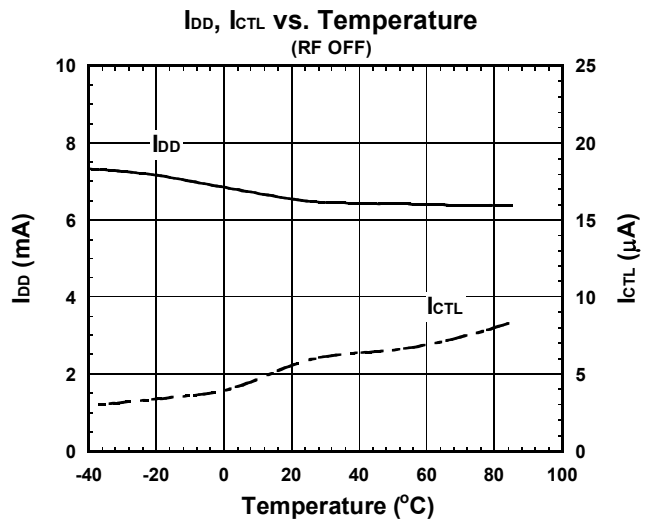
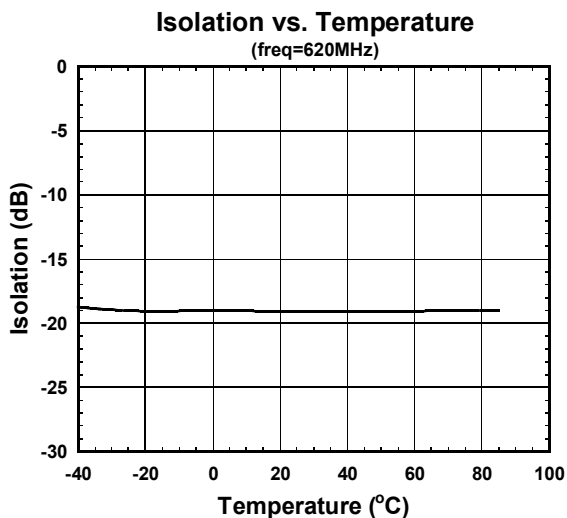
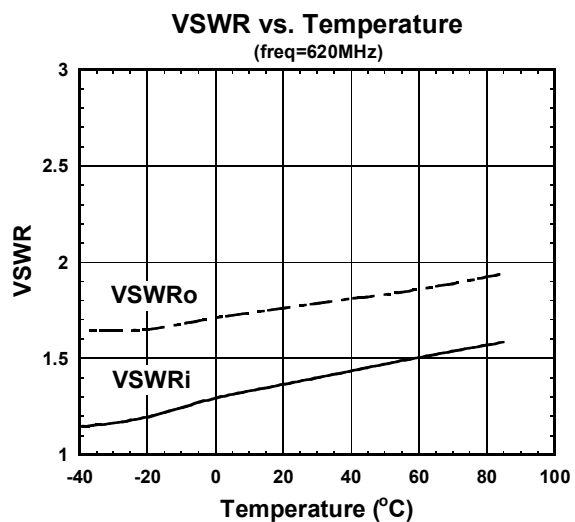
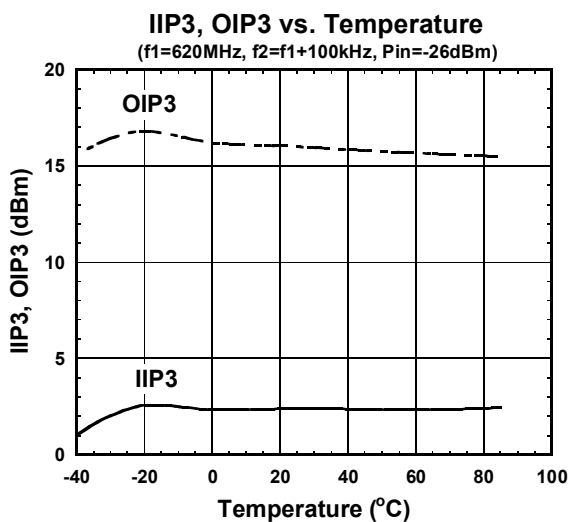
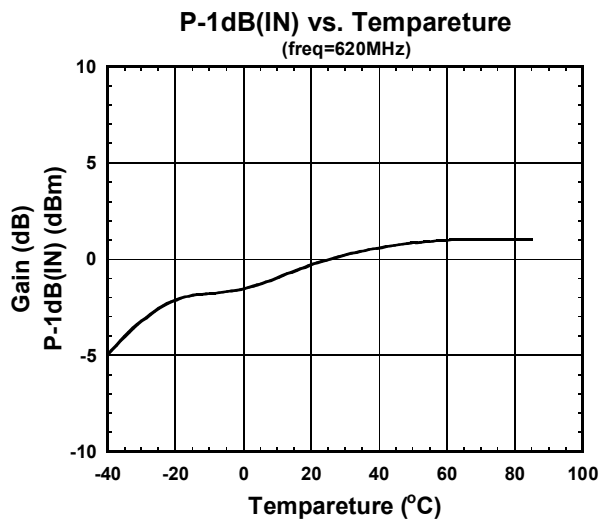
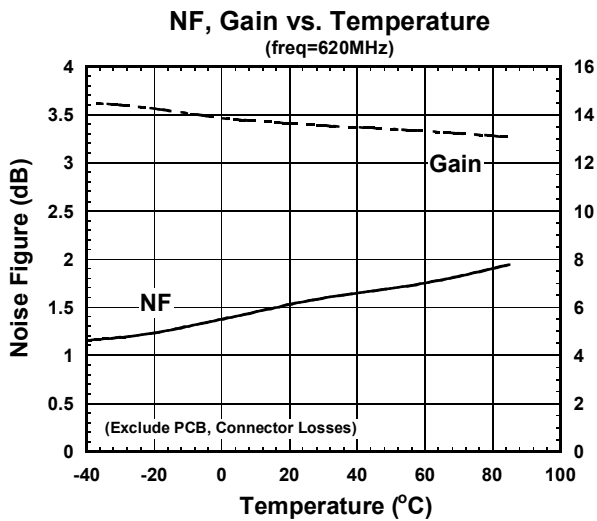
(Condition :  $T_a = +25^\circ\text{C}$ ,  $V_{CTL} = 1.8\text{V}$ ,  $Z_s = Z_l = 50\text{ohm}$ , with application circuit)



# NJG1142KA1

## ■ ELECTRICAL CHARACTERISTICS (High Gain Mode)

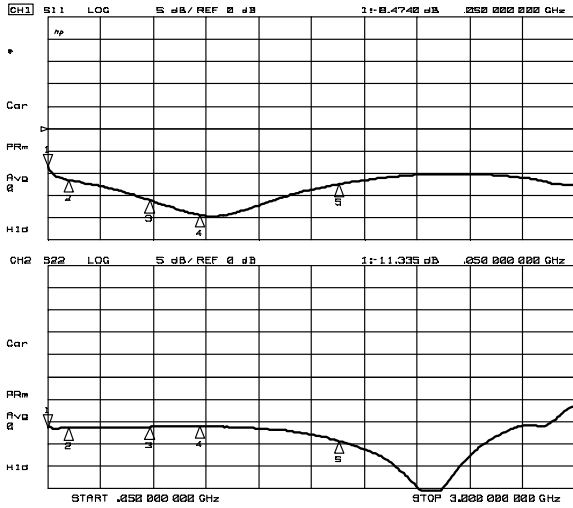
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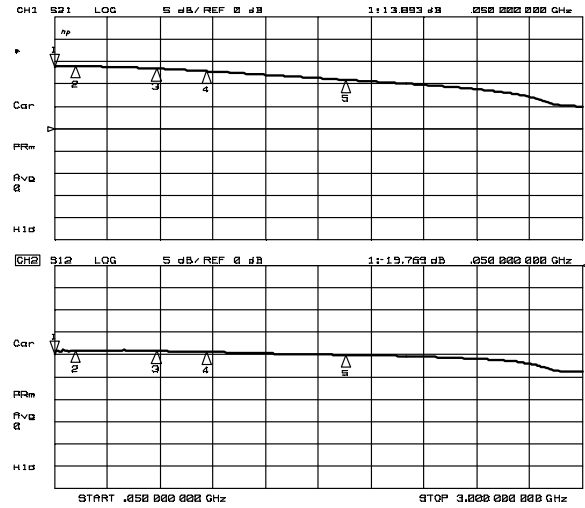


## ELECTRICAL CHARACTERISTICS(High Gain Mode)

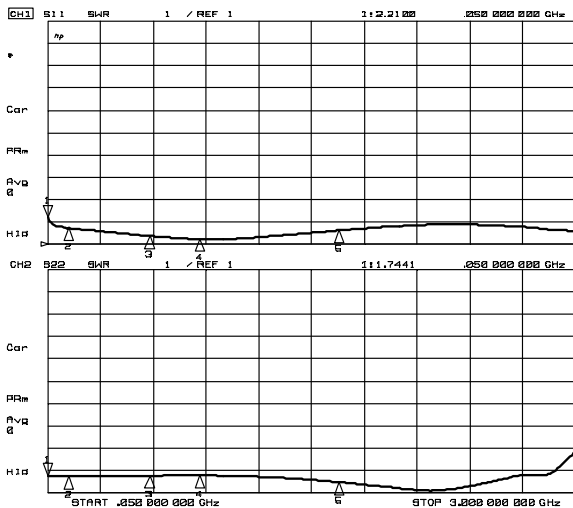
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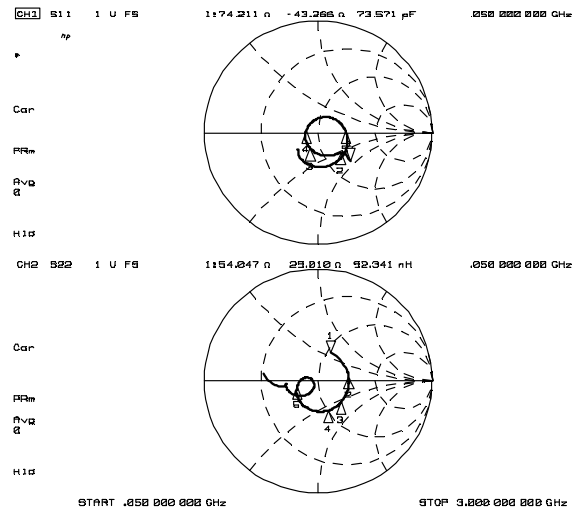
S11, S22



S21, S12



VSWRi, VSWRo

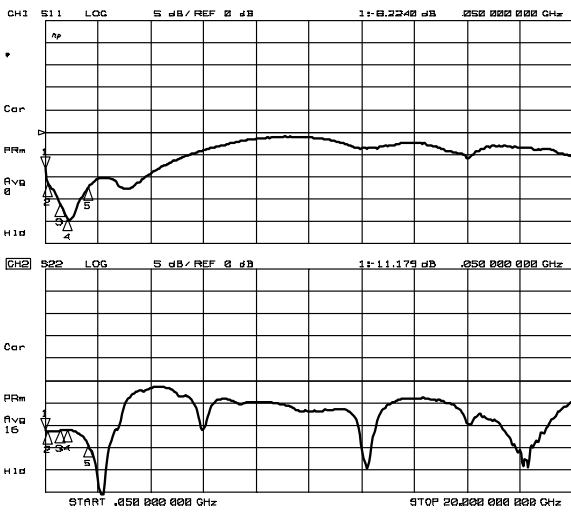


Zin, Zout

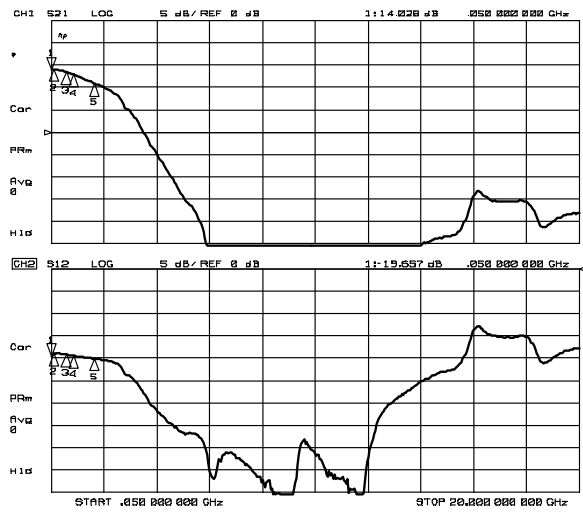
# NJG1142KA1

## ■ ELECTRICAL CHARACTERISTICS (High Gain Mode)

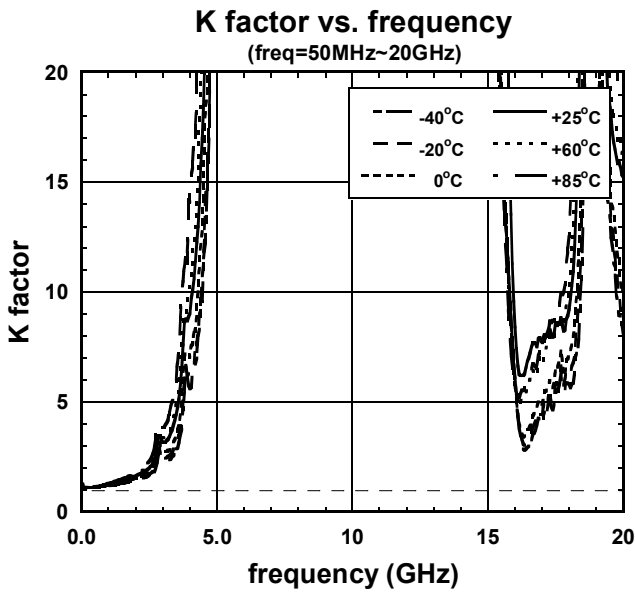
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S11, S22 (50MHz~20GHz)

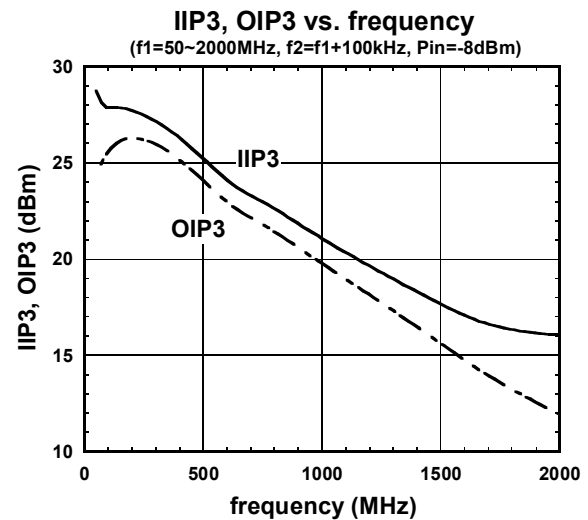
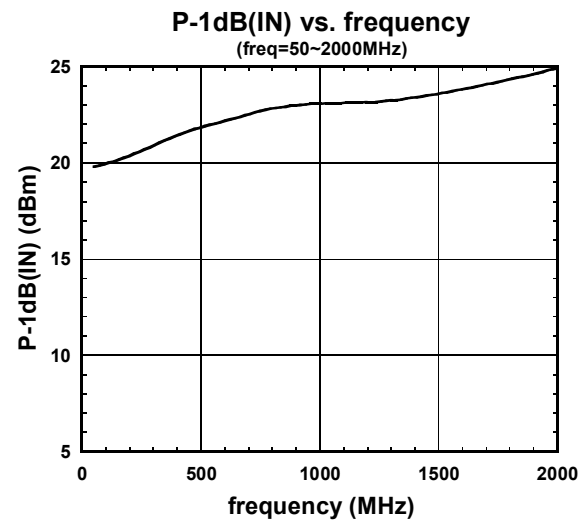
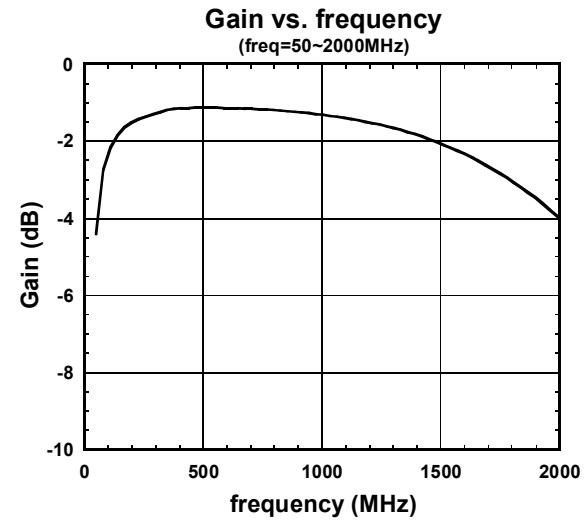
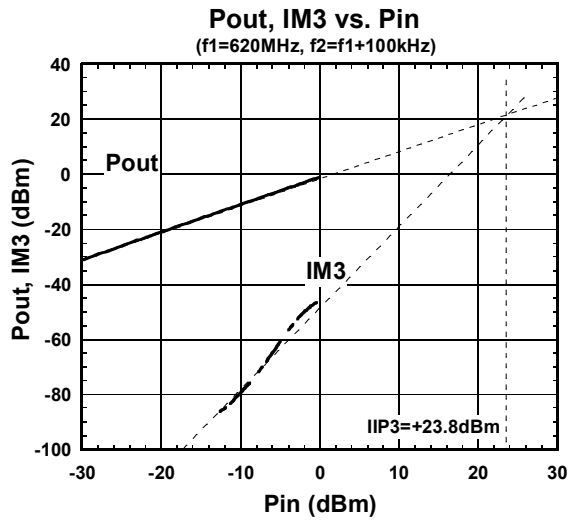
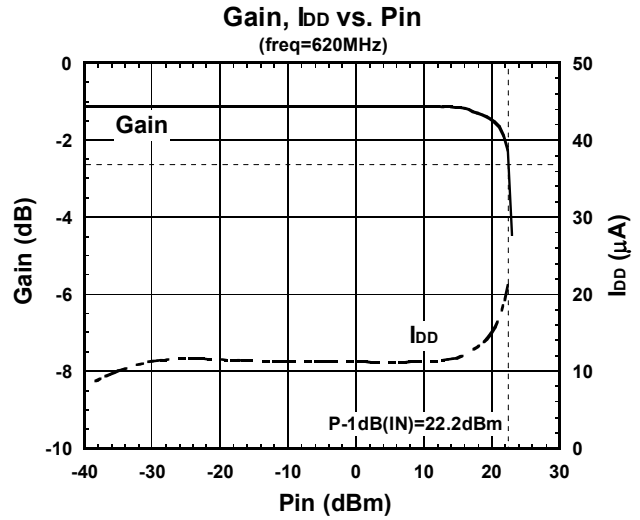
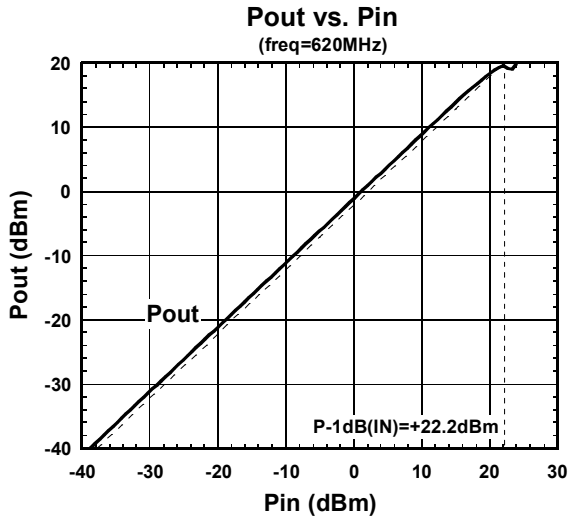


S21, S12 (50MHz~20GHz)



## ■ ELECTRICAL CHARACTERISTICS (Low Gain Mode)

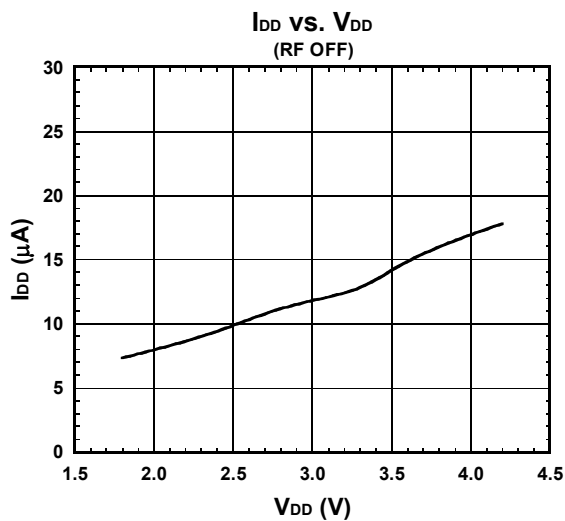
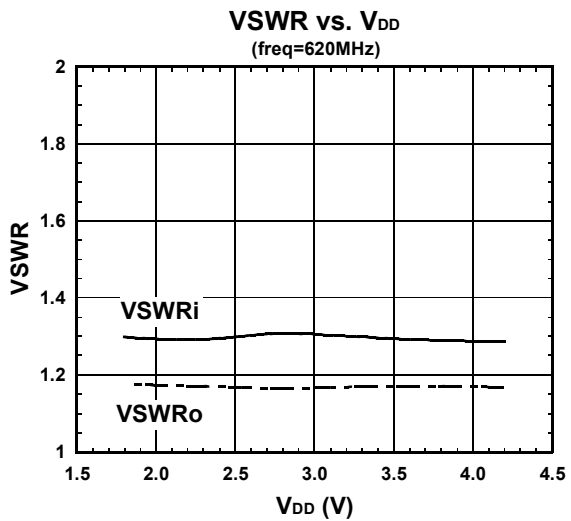
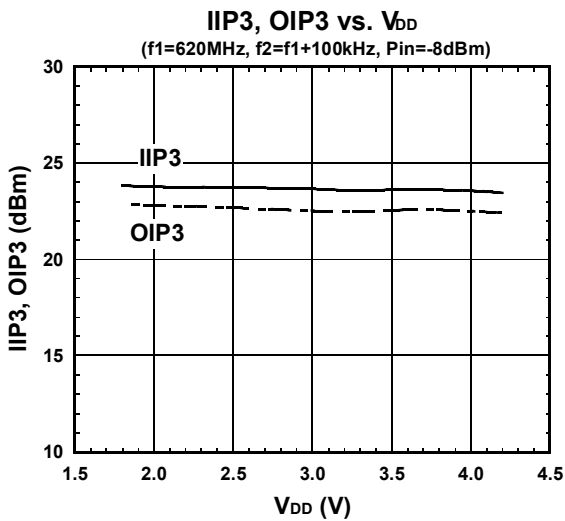
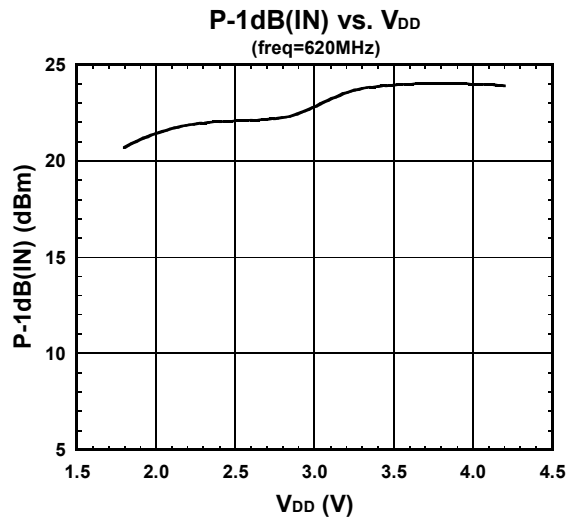
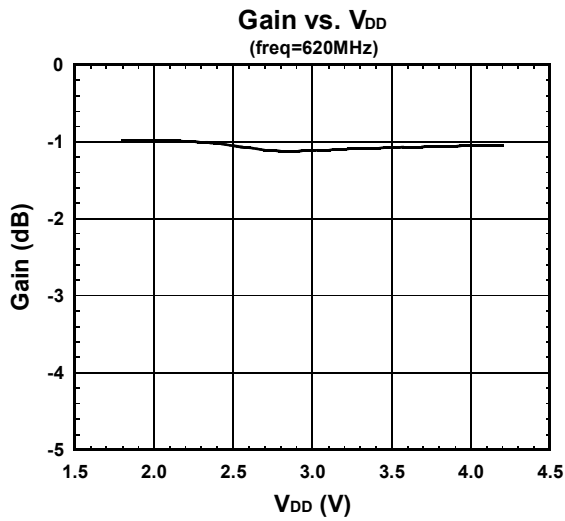
(Condition :  $T_a=+25^\circ\text{C}$ ,  $V_{DD}=2.8\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\text{ohm}$ , with application circuit)



# NJG1142KA1

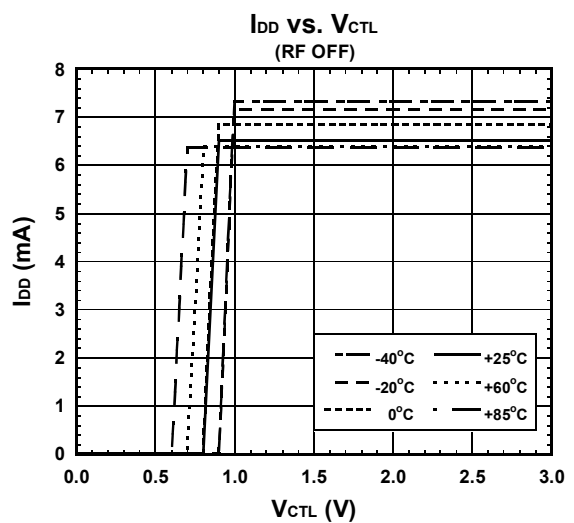
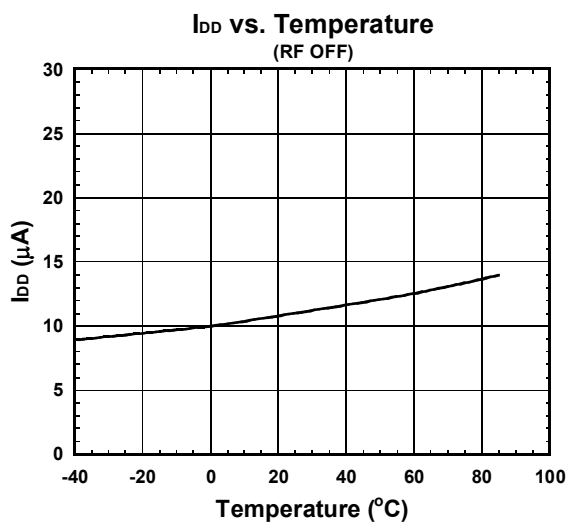
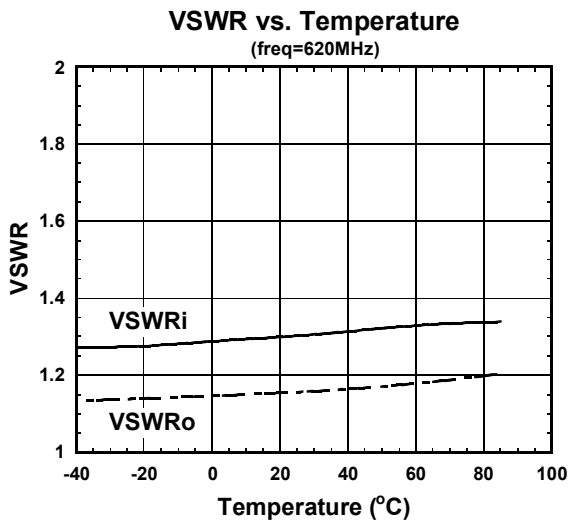
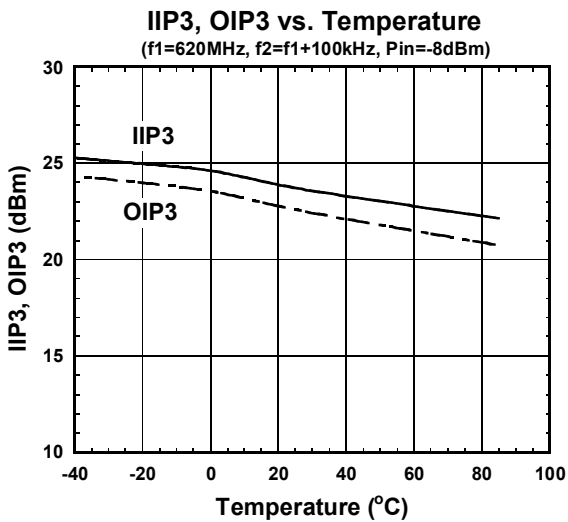
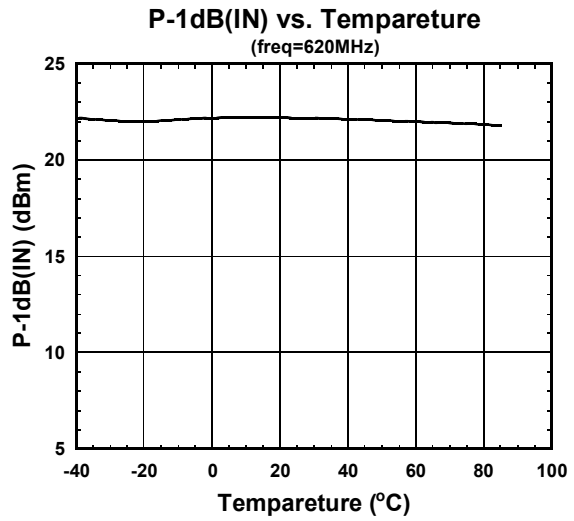
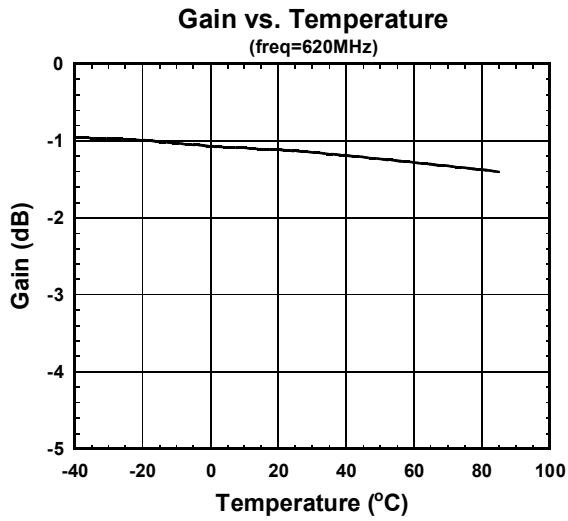
## ■ ELECTRICAL CHARACTERISTICS (Low Gain Mode)

(Condition :  $T_a=+25^{\circ}\text{C}$ ,  $V_{\text{CTL}}=0\text{V}$ ,  $Z_s=Z_l=50\text{ohm}$ , with application circuit)



## ■ ELECTRICAL CHARACTERISTICS (Low Gain Mode)

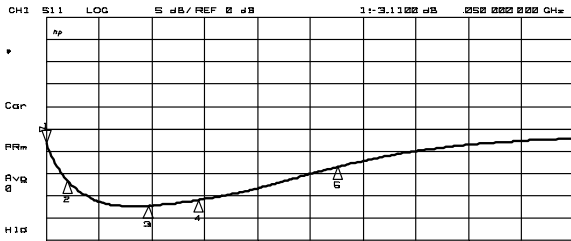
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# NJG1142KA1

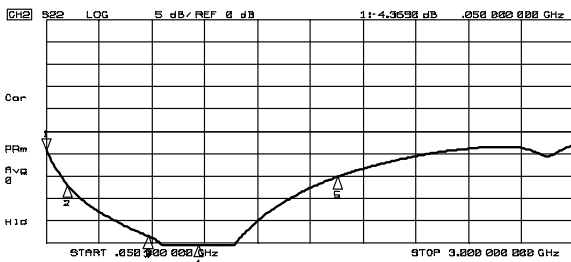
## ELECTRICAL CHARACTERISTICS (Low Gain Mode)

(Condition : Ta=+25°C, V<sub>DD</sub>=2.8V, V<sub>CTL</sub>=0V, Z<sub>s</sub>=Z<sub>l</sub>=50ohm,with application circuit)



CH1 Markers

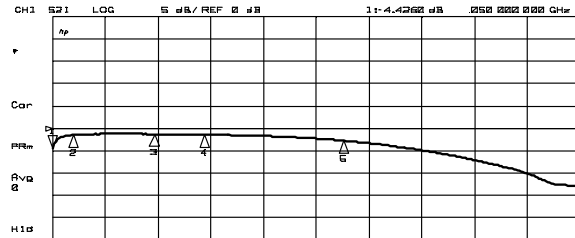
2:	-1.6884 dB	170.000 MHz
3:	-1.7262 dB	620.000 MHz
4:	-1.5099 dB	980.000 MHz
5:	-3.4502 dB	1.60000 GHz



CH2 Markers

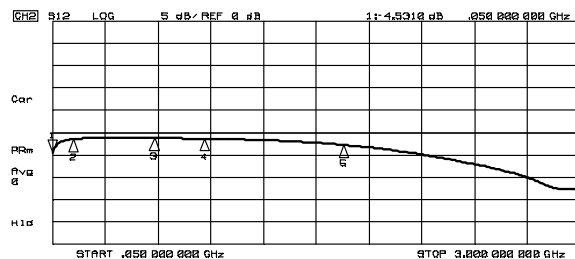
2:	-1.2091 dB	170.000 MHz
3:	-2.1493 dB	620.000 MHz
4:	-3.7096 dB	980.000 MHz
5:	-1.8175 dB	1.60000 GHz

S11, S22



CH1 Markers

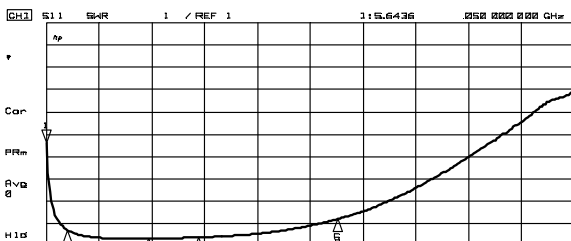
2:	-1.4000 dB	170.000 MHz
3:	-1.2178 dB	620.000 MHz
4:	-1.3520 dB	980.000 MHz
5:	-2.7650 dB	1.60000 GHz



CH2 Markers

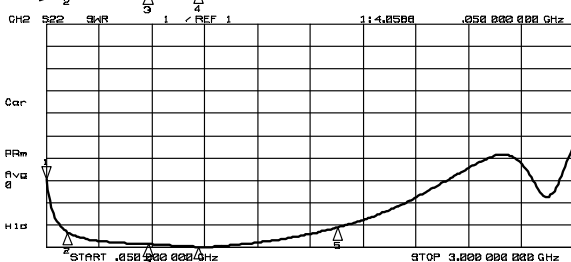
2:	-1.4000 dB	170.000 MHz
3:	-1.2200 dB	620.000 MHz
4:	-1.3560 dB	980.000 MHz
5:	-2.7750 dB	1.60000 GHz

S21, S12



CH1 Markers

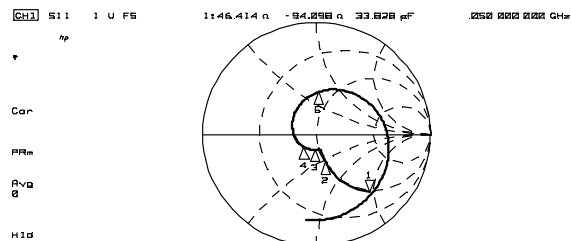
2:	1.7045	170.000 MHz
3:	1.3176	620.000 MHz
4:	1.3813	980.000 MHz
5:	2.2152	1.60000 GHz



CH2 Markers

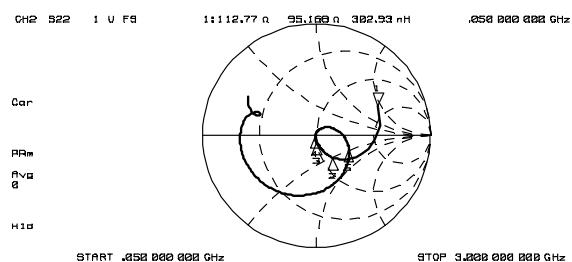
2:	1.6636	170.000 MHz
3:	1.1433	620.000 MHz
4:	1.0283	980.000 MHz
5:	1.0901	1.60000 GHz

VSWRi, VSWRo



CH1 Markers

2:	51.145 n	-27.262 n	170.000 MHz
3:	47.539 n	-13.264 n	620.000 MHz
4:	39.170 n	-5.451 n	980.000 MHz
5:	38.738 n	-24.127 n	1.60000 GHz



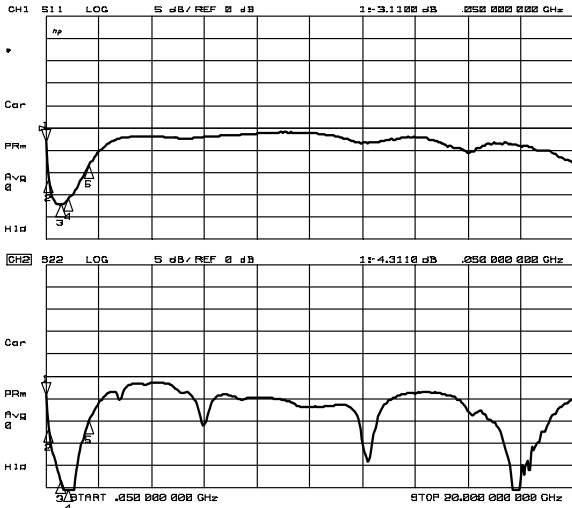
CH2 Markers

2:	60.990 n	-26.195 n	170.000 MHz
3:	49.853 n	-6.093 n	620.000 MHz
4:	48.693 n	-443.36 nH	980.000 MHz
5:	88.594 n	-23.488 n	1.60000 GHz

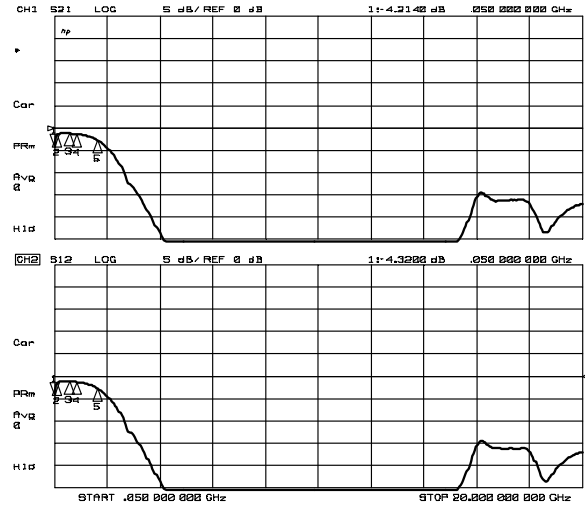
Zin, Zout

## ■ ELECTRICAL CHARACTERISTICS (Low Gain Mode)

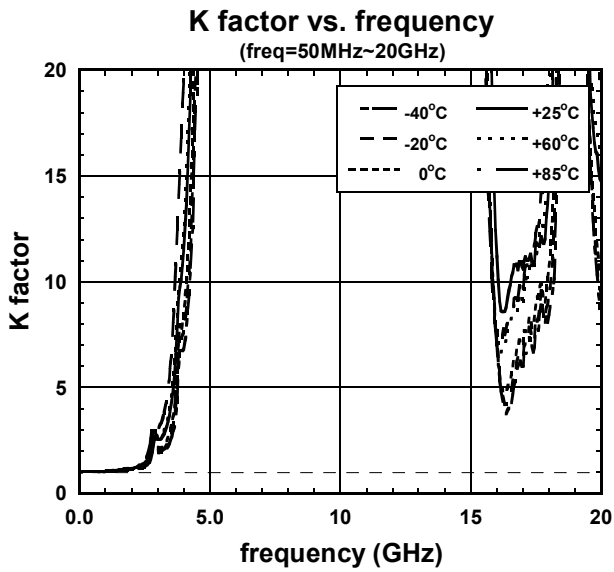
(Condition :  $T_a=+25^{\circ}\text{C}$ ,  $V_{DD}=2.8\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\text{ohm}$ , With application circuit)



S11, S22 (50MHz~20GHz)

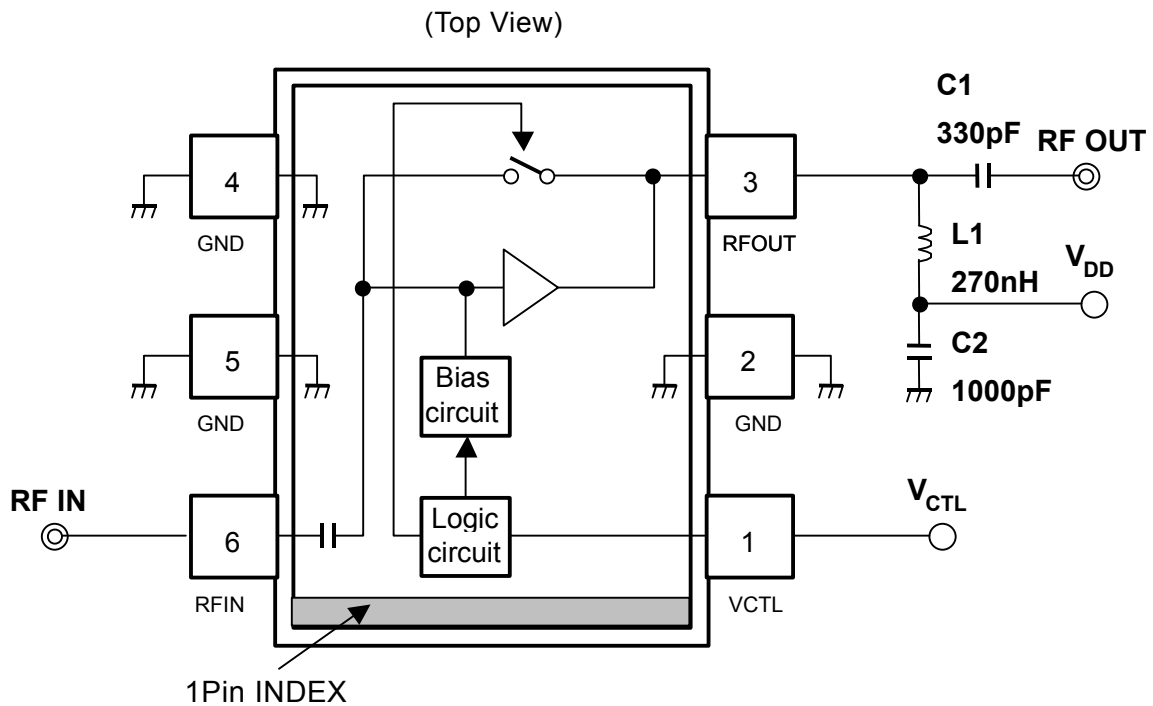


S21, S12 (50MHz~20GHz)



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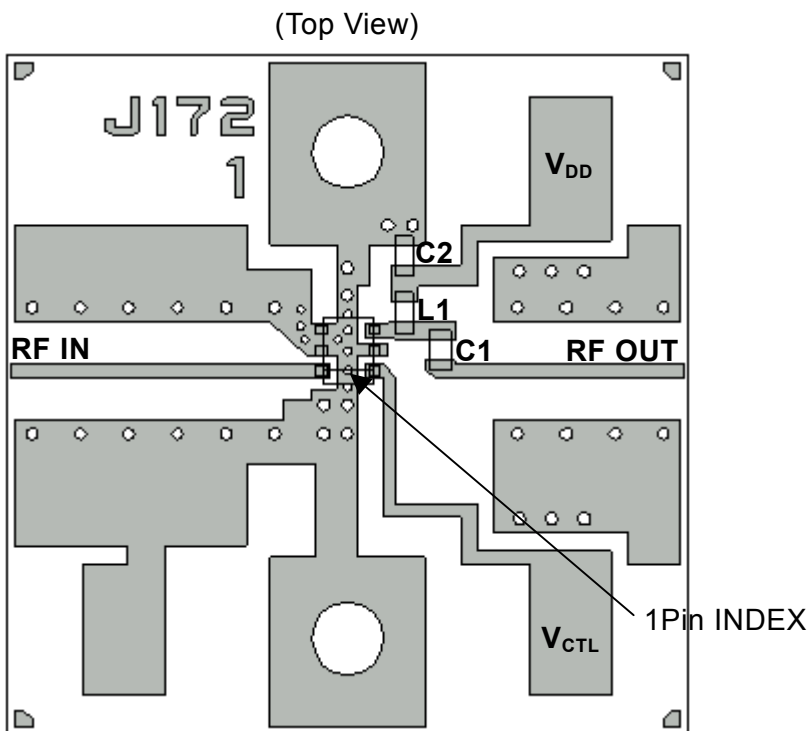
## APPLICATION CIRCUIT



### NOTES:

- L1 is an RF choke. (DC feed inductor)
- C1 is a coupling and DC blocking capacitor at the output.
- C2 is a bypass capacitor.

## TEST PCB LAYOUT



### PARTS LIST

Parts ID.	Notes
L1	TAIYO-YUDEN HK1005 Series
C1, C2	MURATA GRM15 Series

PCB (FR-4):  
 $t=0.2\text{mm}$   
 MICROSTRIP LINE WIDTH  
 $=0.40\text{mm}$  ( $Z_0=50\Omega$ )  
 PCB SIZE= $16.8\text{mm} \times 16.8\text{mm}$

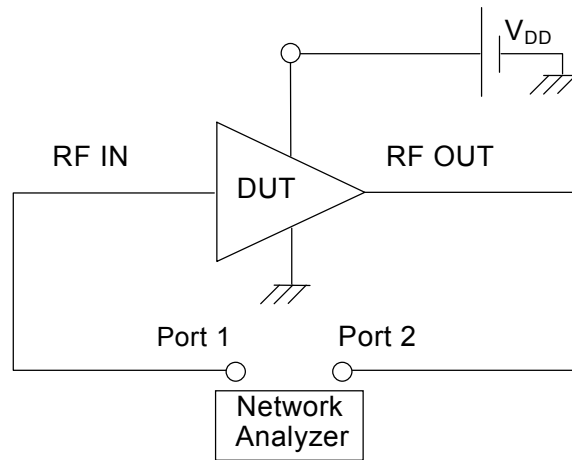
### PRECAUTION:

- In order not to couple with terminal RFIN and RFOUT, please layout ground pattern under the IC.



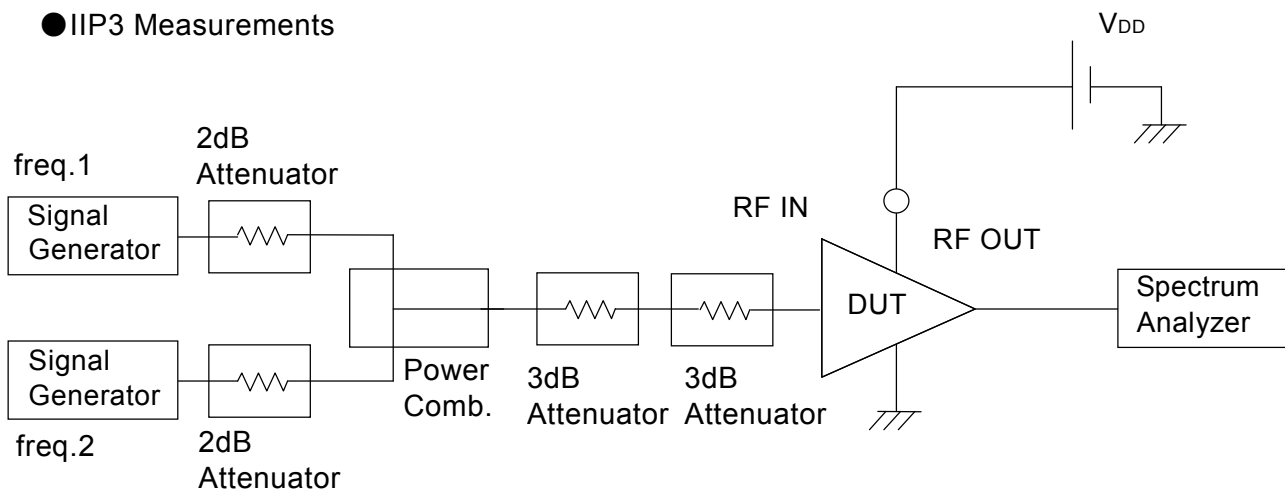
## MEASUREMENT BLOCK DIAGRAM

### S parameter Measurements

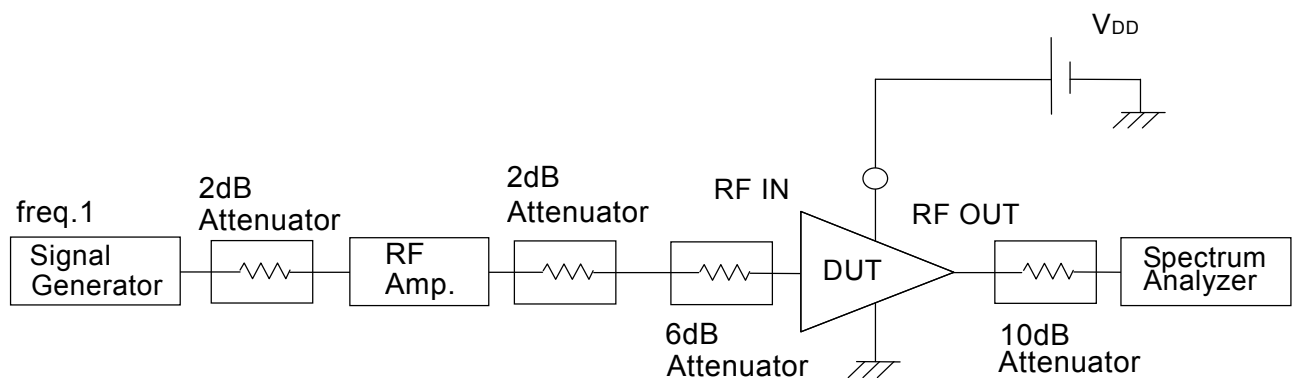


S parameter Measurement Block Diagram

### IIP3 Measurements



IF and IM3 Measurement Block Diagram for IIP3 (High Gain Mode)



IF and IM3 Measurement Block Diagram for IIP3 (Low Gain Mode)

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## ● Noise Figure Measurements

### Measuring instruments

NF Analyzer : Agilent 8973A  
Noise Source : Agilent 346A

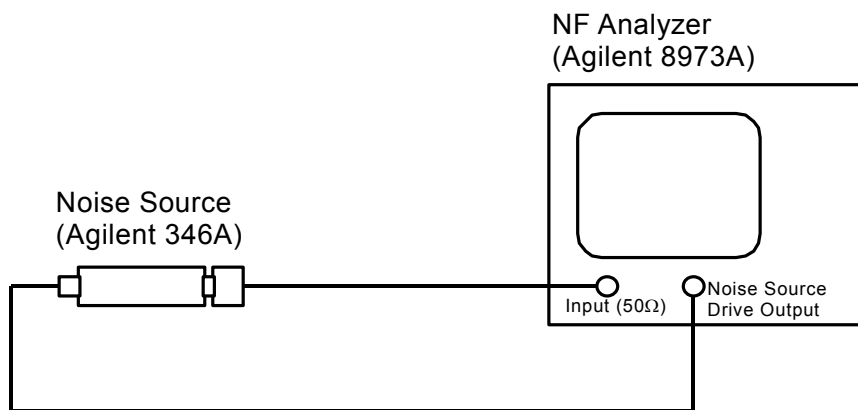
### Setting the NF analyzer

Measurement mode form

Device under test : Amplifier  
System downconverter : off

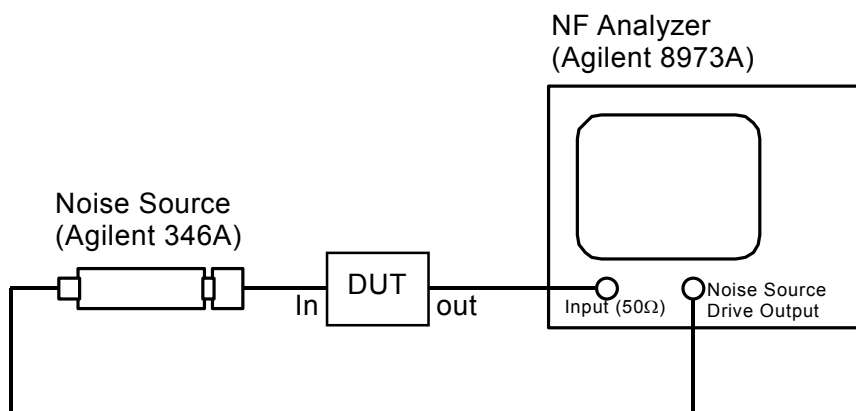
Mode setup form

Sideband : LSB  
Averages : 8  
Average mode : Point  
Bandwidth : 4MHz  
Loss comp : off  
Tcold : setting the temperature of noise source (300.0K)



\* Noise source and NF analyzer are connected directly.

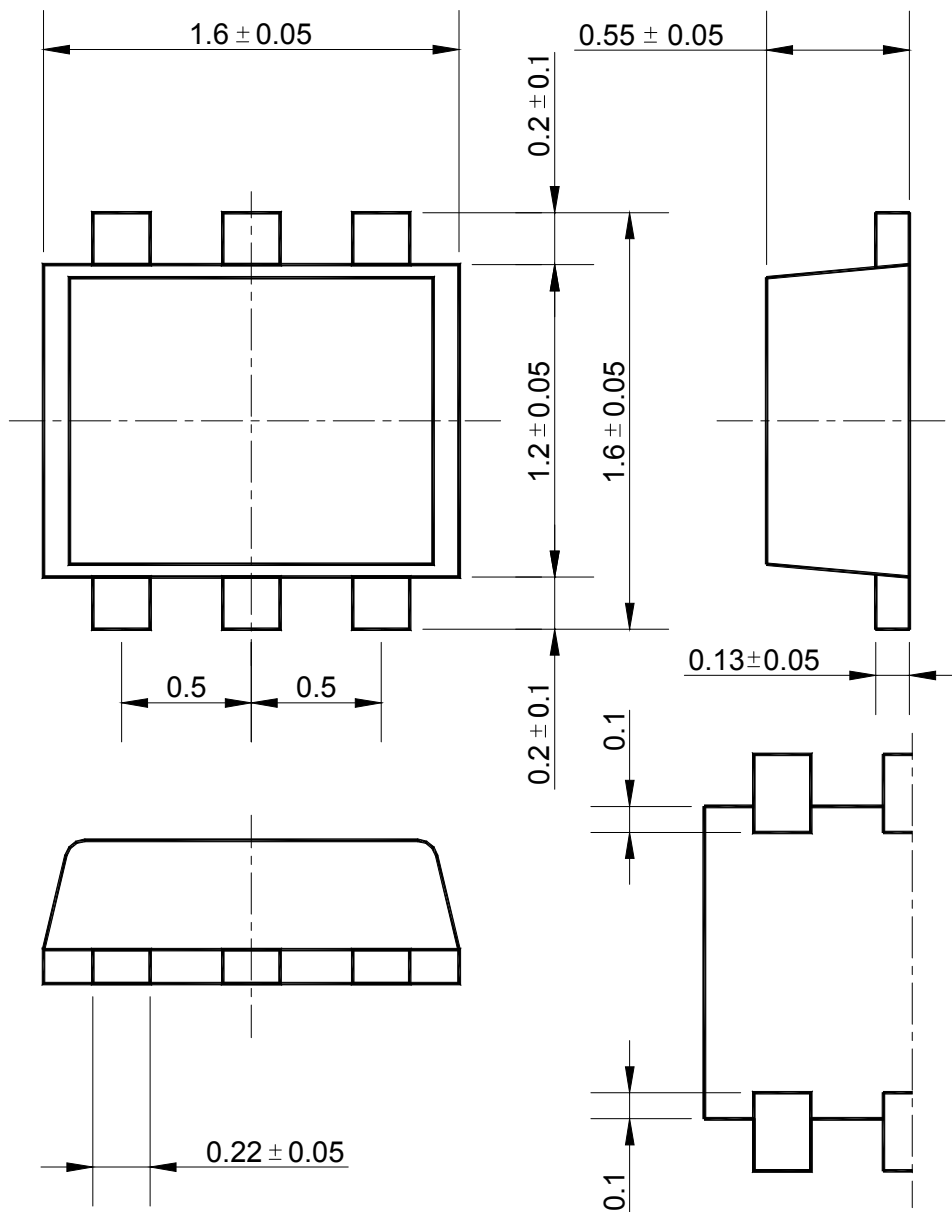
**Calibration Setup**



\* Noise source and DUT, DUT and NF analyzer are connected directly.

**Measurement Setup**

## ■ PACKAGE OUTLINE (FLP6-A1)



Unit: mm

### Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

### [CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.